SUP/SUB65P06-20

Vishay Siliconix



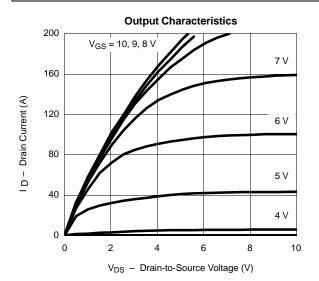
Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Static						•
Drain-Source Breakdown Voltage	V _{(BR)DSS}	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$	-60			- V
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	-2.0	-3.0	-4.0	
Gate-Body Leakage	I _{GSS}	V_{DS} = 0 V, V_{GS} = ± 20 V			±100	nA
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = -60 \text{ V}, V_{GS} = 0 \text{ V}$			-1	μΑ
		$V_{DS} = -60 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 125^{\circ}\text{C}$			-50	
		$V_{DS} = -60 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 175^{\circ}\text{C}$			-150	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = -5 \text{ V}, V_{GS} = -10 \text{ V}$	-120			А
Drain-Source On-State Resistance ^a	「DS(on)	$V_{GS} = -10 \text{ V}, I_D = -30 \text{ A}$		0.017	0.020	Ω
		$V_{GS} = -10 \text{ V, } I_D = -30 \text{ A, } T_J = 125^{\circ}\text{C}$			0.033	
		$V_{GS} = -10$ V, $I_D = -30$ A, $T_J = 175$ °C			0.042	
Forward Transconductancea	9 _{fs}	$V_{DS} = -15 \text{ V}, I_D = -30 \text{ A}$	25			S
Dynamic ^b				•		•
Input Capacitance	C _{iss}	$V_{GS} = 0 \text{ V}, V_{DS} = -25 \text{ V}, f = 1 \text{ MHz}$		4500		pF
Output Capacitance	C _{oss}			870		
Reversen Transfer Capacitance	C _{rss}			350		
Total Gate Charge ^c	Qg	$V_{DS} = -30 \text{ V}, V_{GS} = -10 \text{ V}, I_{D} = -65 \text{ A}$		85	120	nC
Gate-Source Charge ^c	Q _{gs}			24		
Gate-Drain Charge ^c	Q _{gd}			22		
Turn-On Delay Time ^c	t _{d(on)}	$V_{DD} = -30 \text{ V, } R_L = 0.47 \ \Omega$ $I_D \approx -65 \ \text{A, } V_{GEN} = -10 \ \text{V, } R_G = 2.5 \ \Omega$		15	40	- ns
Rise Time ^c	t _r			40	80	
Turn-Off Delay Time ^c	t _{d(off)}			65	120	
Fall Time ^c	t _f			30	60	
Source-Drain Diode Ratings ar	nd Characteristic	es (T _C = 25°C) ^b				
Continuous Current	Is				-65	^
Pulsed Current	I _{SM}				-200	A
Forward Voltage ^a	V _{SD}	$I_F = -65 \text{ A}, V_{GS} = 0 \text{ V}$		-1.1	-1.4	V
Reverse Recovery Time	t _{rr}			70	120	ns
Peak Reverse Recovery Current	I _{RM(REC)}	$I_F = -65 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s}$		7	9	Α
Reverse Recovery Charge	Q _{rr}			0.245	0.54	μC

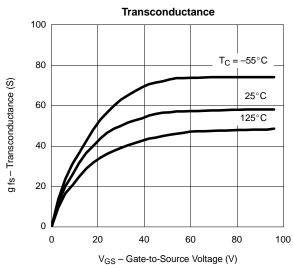
- Notes: a. Pulse test; pulse width $\leq 300~\mu s$, duty cycle $\leq 2\%$. b. Guaranteed by design, not subject to production testing d. Independent of operating temperature.

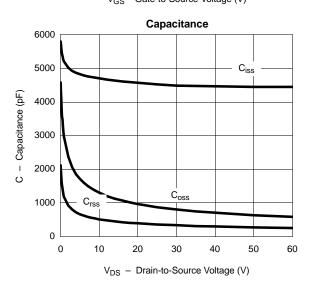


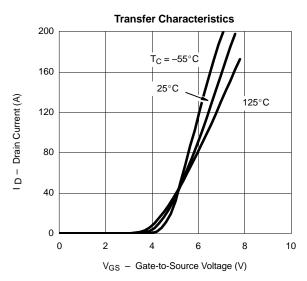
Vishay Siliconix

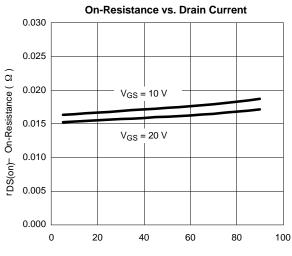
TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)

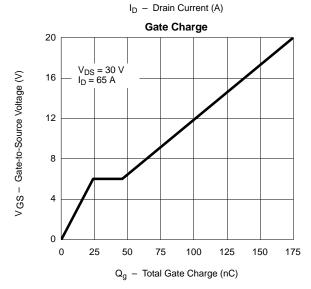








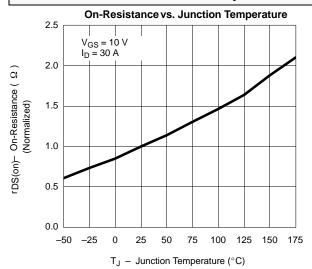


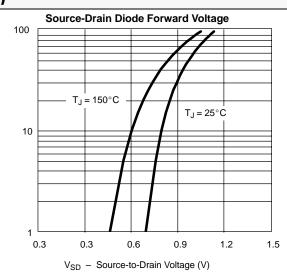


Vishay Siliconix

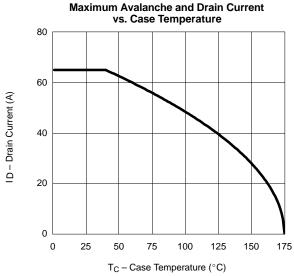


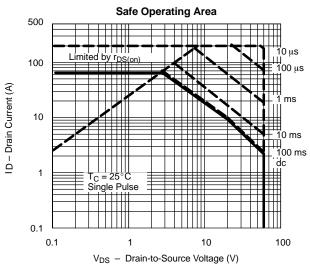
TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)

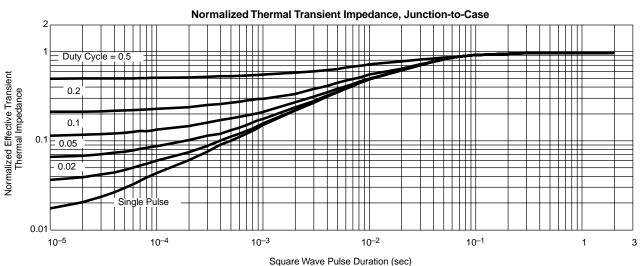




THERMAL RATINGS







S - Source Current (A)



Vishay

Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.

Revision: 18-Jul-08

Document Number: 91000 www.vishay.com